CMOS Analog Switches

DESCRIPTION

The DG300B, DG303B family of monolithic CMOS switches feature three switch configuration options (SPST, SPDT, and DPST) for precision applications in communications, instrumentation and process control, where low leakage switching combined with low power consumption are required.

Designed on the Vishay Siliconix PLUS-40 CMOS process, these switches are latch-up proof, and are designed to block up to 30 V peak-to-peak when off. An epitaxial layer prevents latchup.

In the on condition the switches conduct equally well in both directions (with no offset voltage) and minimize error conditions with their low on-resistance.

Featuring low power consumption (3.5 mW typ.) these switches are ideal for battery powered applications, without sacrificing switching speed. Designed for break-before-make switching action, these devices are CMOS and quasi TTL compatible. Single supply operation is allowed by connecting the V- rail to 0 V.

FEATURES

- Analog signal range: ± 15 V
- Fast switching - t_{ON}: 150 ns
- Low on-resistance - $R_{DS(on)}$: 30 Ω
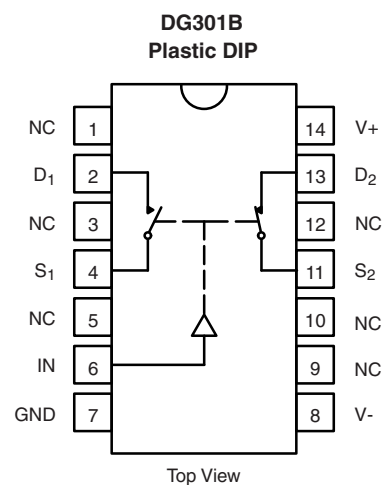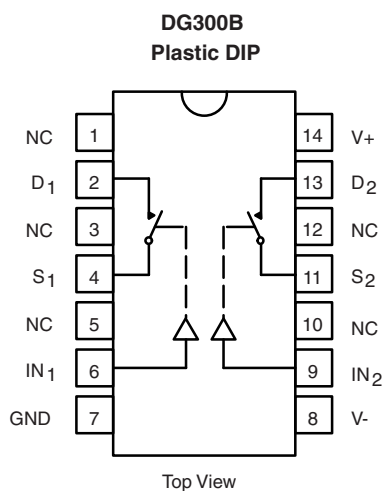- Single supply operation
- Latch-up proof
- CMOS compatible

BENEFITS

- Full rail-to-rail analog signal range
- Low signal error
- Low power dissipation

APPLICATIONS

- Low level switching circuits
- Programmable gain amplifiers
- Portable and battery powered systems

**RoHS*
COMPLIANT**

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

**DG300B
Plastic DIP**

NC	1		14	V+
D_1	2		13	D_2
NC	3		12	NC
S_1	4		11	S_2
NC	5		10	NC
IN_1	6		9	IN_2
GND	7		8	V-

Top View

**DG301B
Plastic DIP**

NC	1		14	V+
D_1	2		13	D_2
NC	3		12	NC
S_1	4		11	S_2
NC	5		10	NC
IN	6		9	NC
GND	7		8	V-

Top View

TRUTH TABLE

Logic	Switch
0	OFF
1	ON

Logic "0" ≤ 0.8 V
Logic "1" ≥ 4 V

TRUTH TABLE

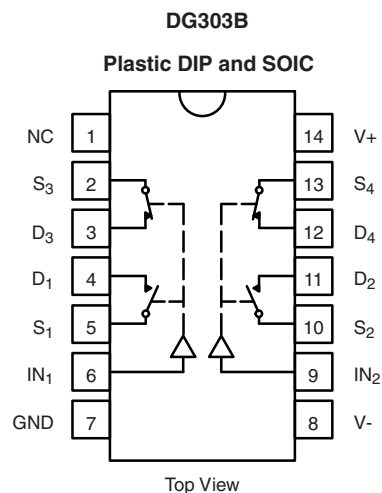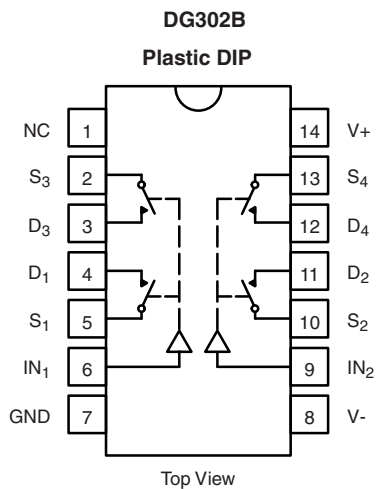| Logic	SW_1	SW_2
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 0.8 V
Logic "1" ≥ 4 V

* Pb containing terminations are not RoHS compliant, exemptions may apply.

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG302B

Plastic DIP

NC	1	14	V+
S_3	2	13	S_4
D_3	3	12	D_4
D_1	4	11	D_2
S_1	5	10	S_2
IN_1	6	9	IN_2
GND	7	8	V-

Top View

DG303B

Plastic DIP and SOIC

NC	1	14	V+
S_3	2	13	S_4
D_3	3	12	D_4
D_1	4	11	D_2
S_1	5	10	S_2
IN_1	6	9	IN_2
GND	7	8	V-

Top View

TRUTH TABLE

Logic	Switch
0	OFF
1	ON

Logic "0" $\leq$ 0.8 V
Logic "1" $\geq$ 4 V

TRUTH TABLE

Logic	SW_1, SW_2	SW_3, SW_4
0	OFF	ON
1	ON	OFF

Logic "0" $\leq$ 0.8 V
Logic "1" $\geq$ 4 V

ORDERING INFORMATION

Temp. Range	Standard Package	Standard Part Number	Lead (Pb)-free Part Number
- 40 °C to 85 °C	14-Pin Plastic DIP	DG300BDJ	DG300BDJ-E3
		DG301BDJ	DG301BDJ-E3
		DG302BDJ	DG302BDJ-E3
		DG303BDJ	DG303BDJ-E3
	14-SOIC	DG303BDY	DG303BDY-T1 DG303BDY-E3 DG303BDY-T1-E3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

Parameter		Limit	Unit
Voltages Referenced V+ to V-		44	V
GND		25	
Digital Inputs[a], V_S, V_D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current (Any Terminal)		30	mA
Continuous Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature		- 65 to 150	°C
Power Dissipation (Package)[b]	14-Pin PlasticDIP[c]	470	mW
	SOIC-14[d]	600	

Notes:
a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 6.5 mW/°C above 25 °C
d. Derate 7.6 mW/°C above 75 °C.

SCHEMATIC DIAGRAM (Typical Channel)
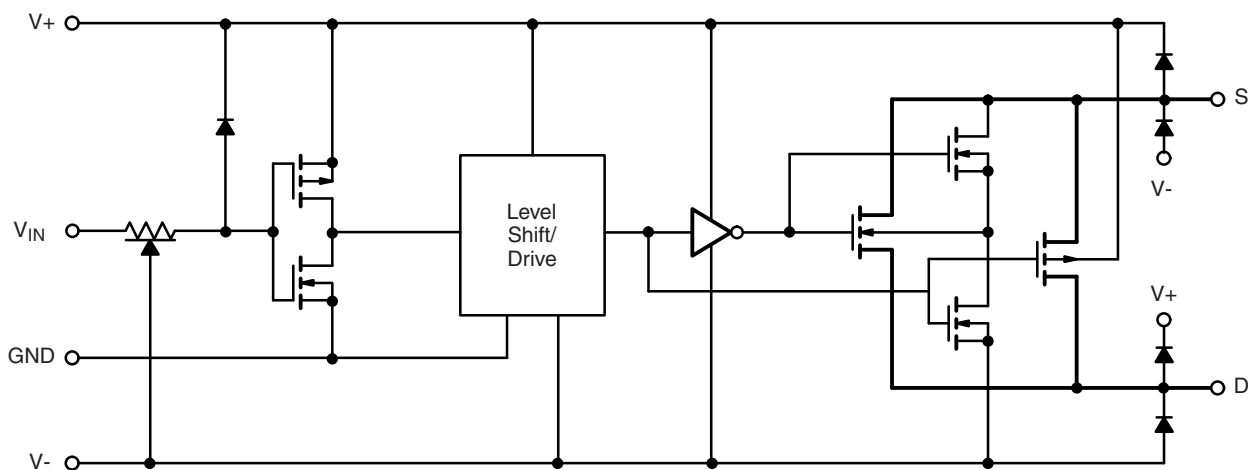
Figure 1.

SPECIFICATIONS[a]

| Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V V_{IN} = 0.8 V or V_{IN} = 4 V[f]		Temp.[b]	Limits - 40 °C to 85 °C Min.[d]	Typ.[c]	Max.[d]	Unit
Analog Switch								
Analog Signal Range[e]	V_{ANALOG}			Full	- 15		15	V
Drain-Source On-Resistance	$R_{DS(on)}$	V_D = ± 10 V, I_S = - 10 mA		Room Full		30	50 75	Ω
Source Off Leakage Current	$I_{S(off)}$	V_S = ± 14 V, V_D = ± 14 V		Room Hot	- 5 - 100	± 0.1	5 100	nA
Drain Off Leakage Current	$I_{D(off)}$			Room Hot	- 5 - 100	± 0.1	5 100	
Drain On Leakage Current	$I_{D(on)}$	V_S = V_D = ± 14 V		Room Hot	- 5 - 100	± 0.1	5 100	
Digital Control								
Input Current with Input Voltage High	I_{INH}	V_{IN} = 5 V		Room Full	- 1	- 0.001		µA
		V_{IN} = 15 V		Room Full		0.001	1	
Input Current with Input Voltage Low	I_{INL}	V_{IN} = 0 V		Room Full	- 1	- 0.001		
Dynamic Characteristics								
Turn-On Time	t_{ON}	see figure 2		Room		150		ns
Turn-Off Time	t_{OFF}			Room		130		
Break-Before-Make Time	t_{OPEN}	DG301B, DG303B Only figure 3		Room		50		
Charge Injection	Q	C_L = 1 nF, R_{gen} = 0 Ω, V_{gen} = 0 V figure 4		Room		8		pC
Source Off Capacitance	$C_{S(off)}$	V_S, V_D = 0 V, f = 1 MHz		Room		14		pF
Drain Off Capacitance	$C_{D(off)}$			Room		14		
Channel-On Capacitance	$C_{D(on)}$			Room		40		
Input Capacitance	C_{in}	f = 1 MHz	V_{IN} = 0 V	Room		6		
			V_{IN} = 15 V	Room		7		
Off Isolation	OIRR	V_{IN} = 0 V, R_L = 1 kΩ		Room		62		dB
Crosstalk (Channel-to-Channel)	X_{TALK}	V_S = 1 V_{rms}, f = 500 kHz		Room		74		
Power Supplies								
Positive Supply Current	I+	V_{IN} = 4 V (one input) all others = 0 V		Room Full		0.23	1	mA
Negative Supply Current	I-			Room Full	- 100	- 0.001		
Positive Supply Current	I+	V_{IN} = 0.8 V (all inputs)		Room Full		0.001	100	µA
Negative Supply Current	I-			Room Full	- 100	- 0.001		

Notes:
a. Refer to PROCESS OPTION FLOWCHART.
b. Room = 25 °C, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Guaranteed by design, not subject to production test.
f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
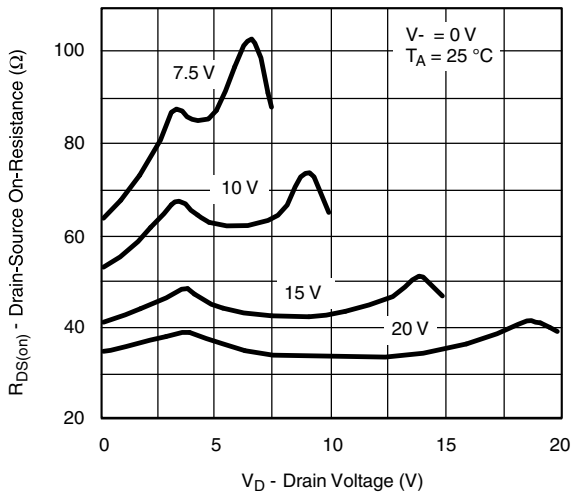
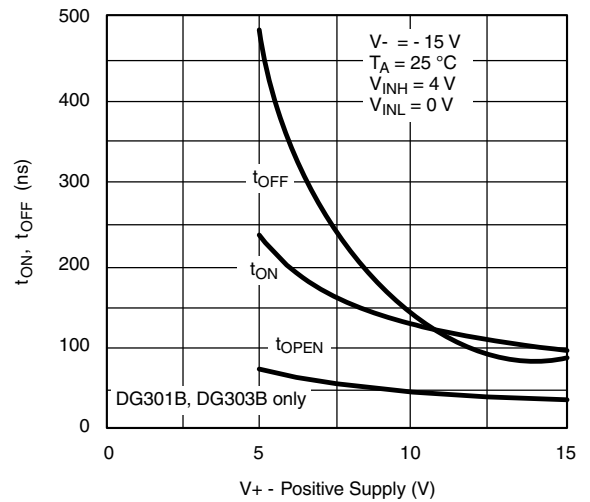## TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)
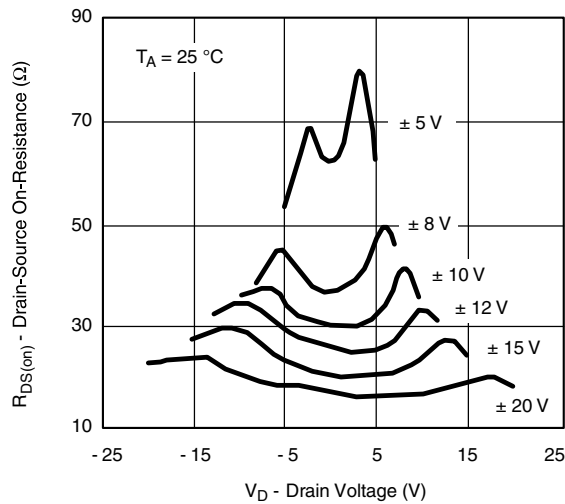
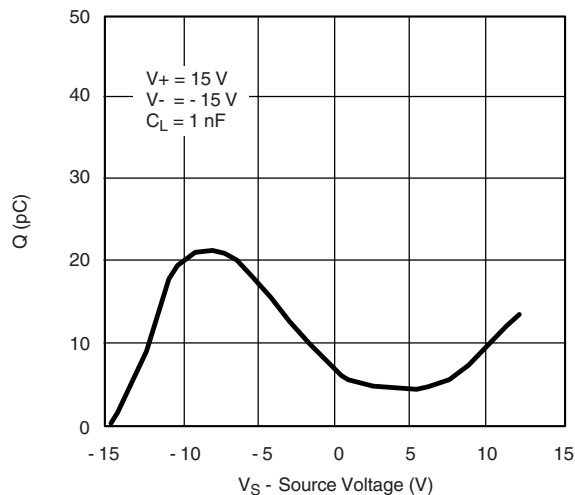**$R_{DS(on)}$ vs. V_D and Power Supply**
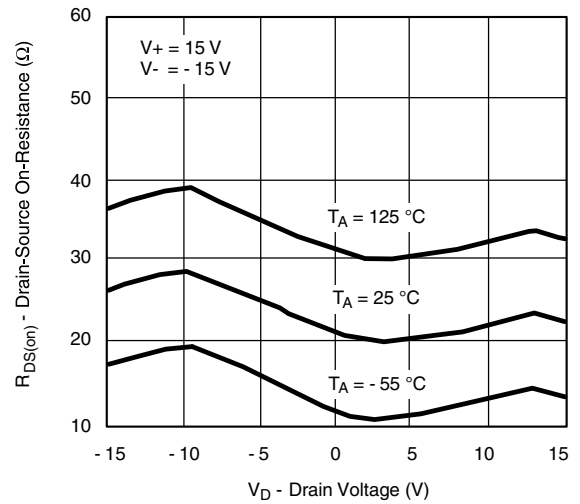
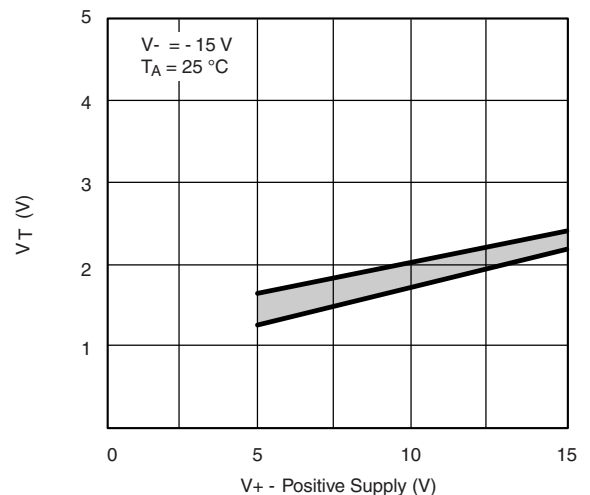**$R_{DS(on)}$ vs. V_D and Temperature**

$R_{DS(on)}$ vs. V_D and Power Supply Voltage

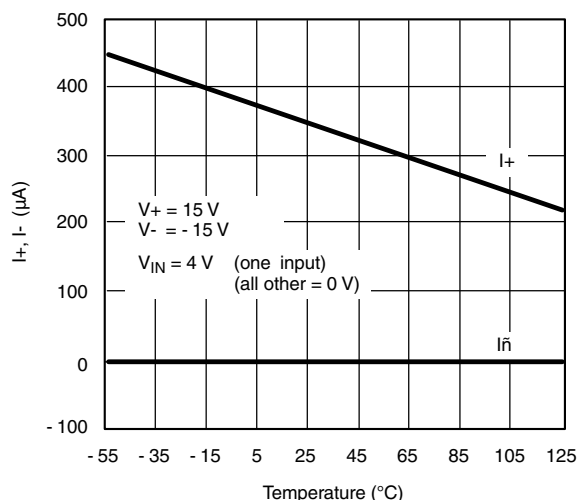**Switching Time and Break-Before-Make Time vs. Positive Supply Voltage**
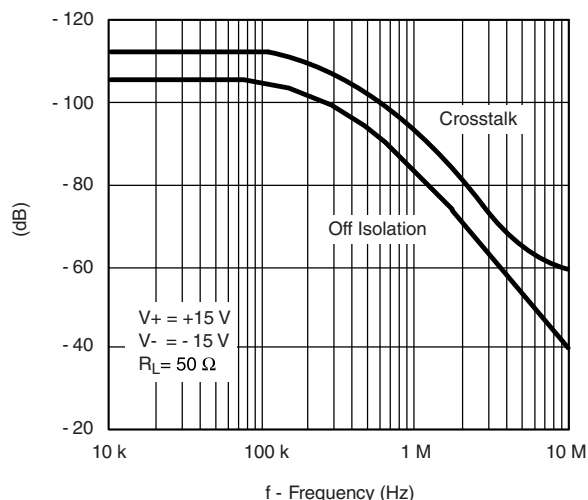

Charge Injection vs. Analog Voltage
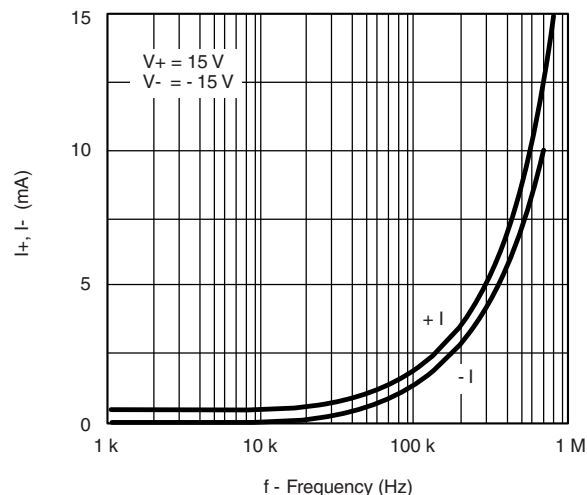

Input Switching Threshold vs. Positive Supply Voltage

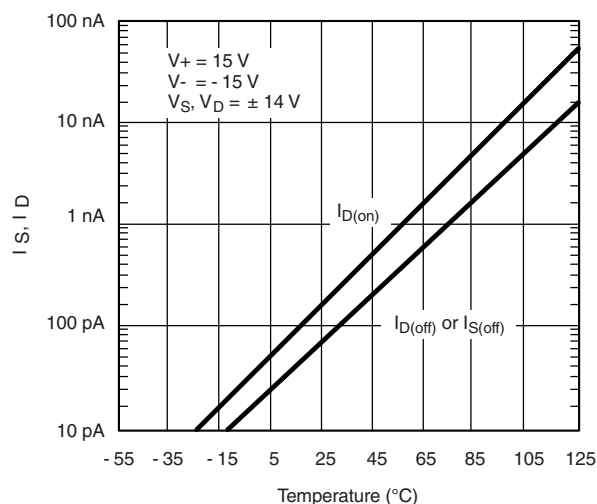## TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

Supply Current vs. Temperature
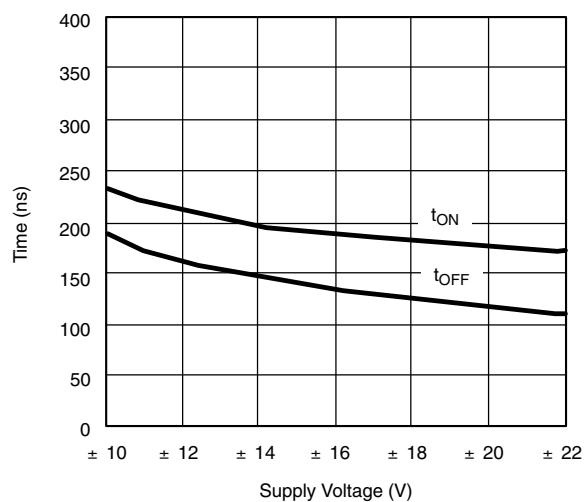
$V+ = 15$ V
$V- = -15$ V

$V_{IN} = 4$ V (one input)
(all other = 0 V)

$I+$
$I\bar{n}$

Off Isolation and Crosstalk vs. Frequency

Crosstalk

Off Isolation

$V+ = +15$ V
$V- = -15$ V
$R_L = 50$ Ω

Supply Curents vs. Switching Frequency

$V+ = 15$ V
$V- = -15$ V

$+ I$
$- I$

Leakage vs. Temperature

$V+ = 15$ V
$V- = -15$ V
$V_S, V_D = \pm 14$ V

$I_{D(on)}$

$I_{D(off)}$ or $I_{S(off)}$

Switching Time vs. Power Supply Voltage

t_{ON}
t_{OFF}
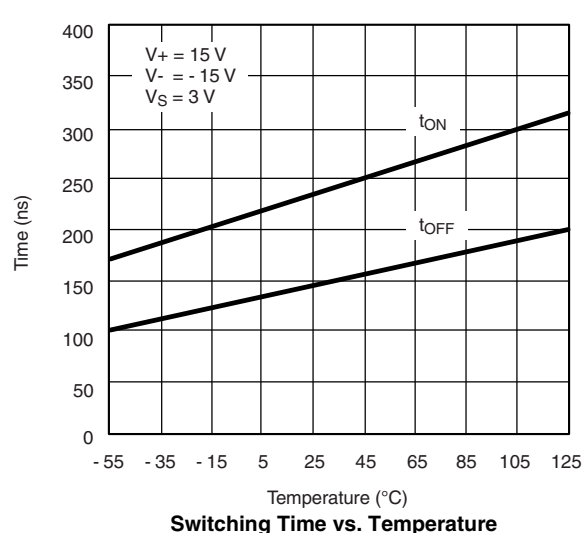
Switching Time vs. Temperature

$V+ = 15$ V
$V- = -15$ V
$V_S = 3$ V

t_{ON}
t_{OFF}

TEST CIRCUITS

C_L (includes fixture and stray capacitance)

$$V_O = V_S \ \frac{R_L}{R_L + r_{DS(on)}}$$

Figure 2. Switching Time
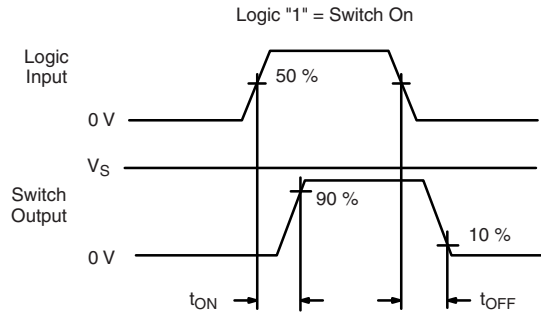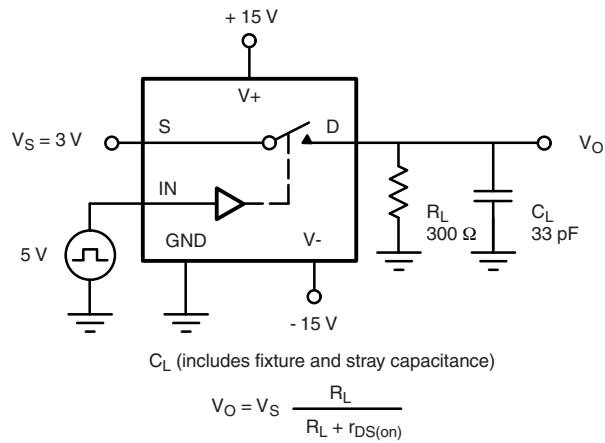
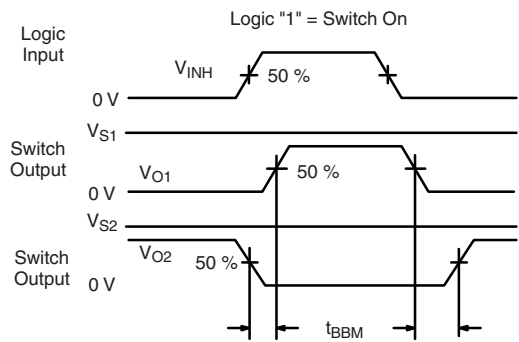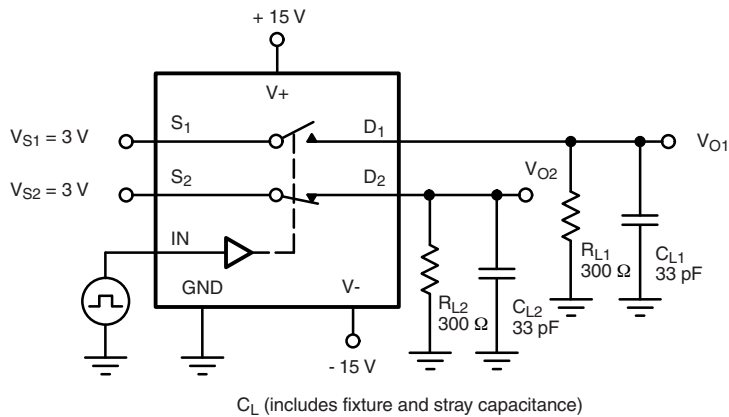C_L (includes fixture and stray capacitance)

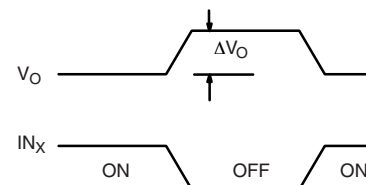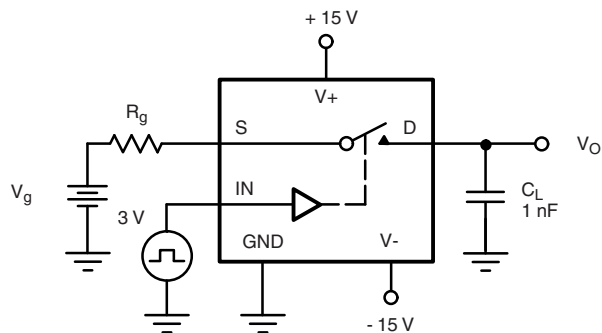**Figure 3. Break-Before-Make SPDT (DG301B, DG303B)**

Figure 4. Charge Injection

APPLICATIONS HINTS[a]

V+ Positive Supply Voltage (V)	V- Negative Supply Voltage (V)	GND Voltage (V)	V_{IN} Logic Input Voltage $V_{INH(min)}/V_{INL(max)}$ (V)	V_S or V_D Analog Voltage Range (V)
15	- 15	0	4/0.8	- 15 to 15
20	- 20	0	4/0.8	- 20 to 20
15	0	0	4/0.8	0 to 15

Notes:
a. Application hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

APPLICATIONS

The DG300B series of analog switches will switch positive analog signals while using a single positive supply. This facilitates their use in applications where only one supply is available. The trade-offs of using single supplies are:

1) Increased $R_{DS(on)}$.
2) Slower switching speed. The analog voltage should not go above or below the supply voltages which in single operation are V+ and 0 V. (See Input Switching Threshold vs. Positive Supply Voltage Curve.)
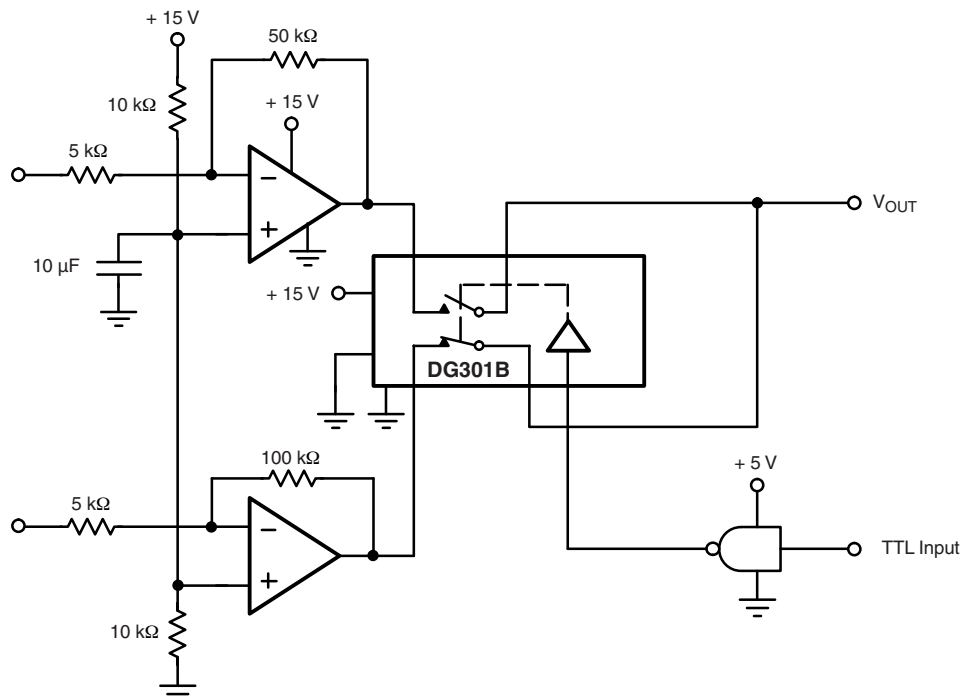

Figure 5. Single Supply Op. Amp. Switching

APPLICATIONS

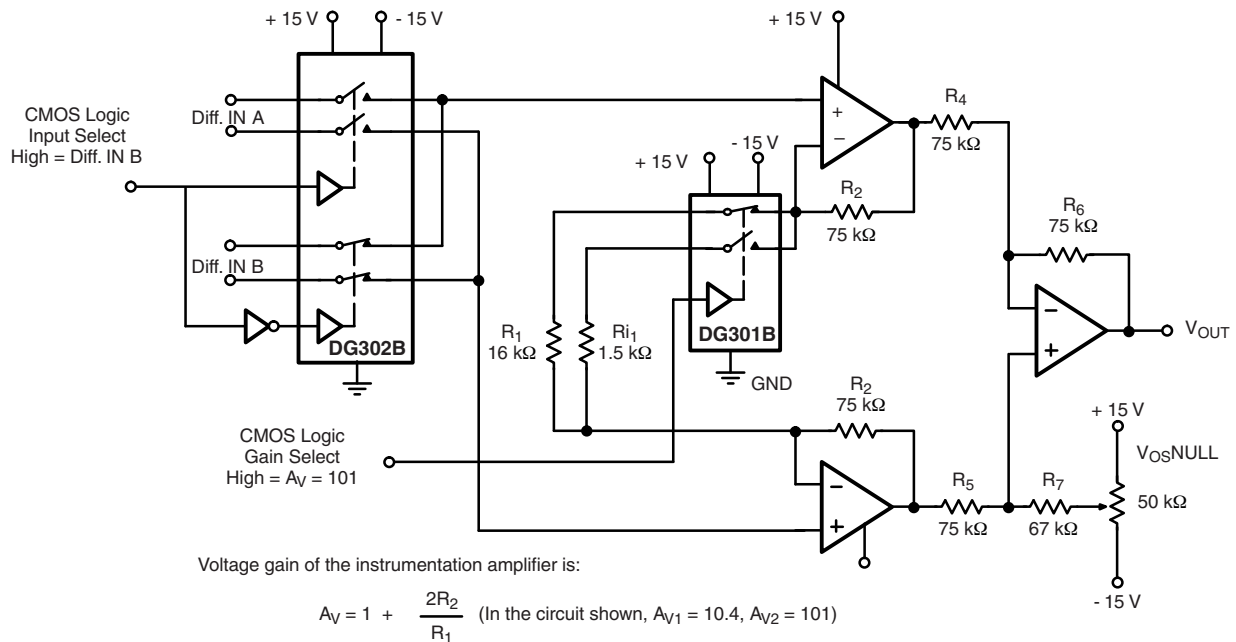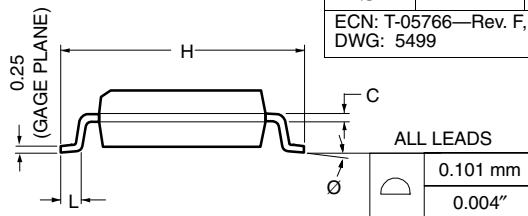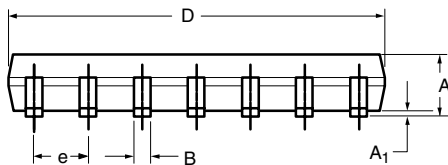Voltage gain of the instrumentation amplifier is:

$$A_V = 1 + \frac{2R_2}{R_1} \quad \text{(In the circuit shown, } A_{V1} = 10.4, A_{V2} = 101\text{)}$$

Figure 6. Low Power Instrumentation Amplifier with Digitally Selectable Inputs and Gain

SOIC (NARROW): 14-LEAD
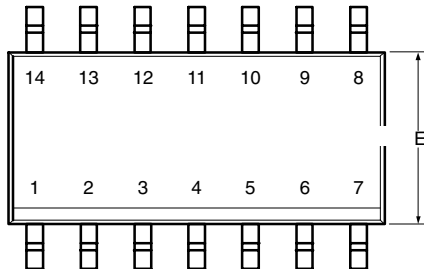
Dim	MILLIMETERS		INCHES	
	Min	**Max**	**Min**	**Max**
A	1.35	1.75	0.053	0.069
A₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	8.55	8.75	0.336	0.344
E	3.8	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: T-05766—Rev. F, 19-Sep-05
DWG: 5499

ALL LEADS

|	
0.101 mm	
0.004″	

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VISHAY

PDIP: 14-LEAD
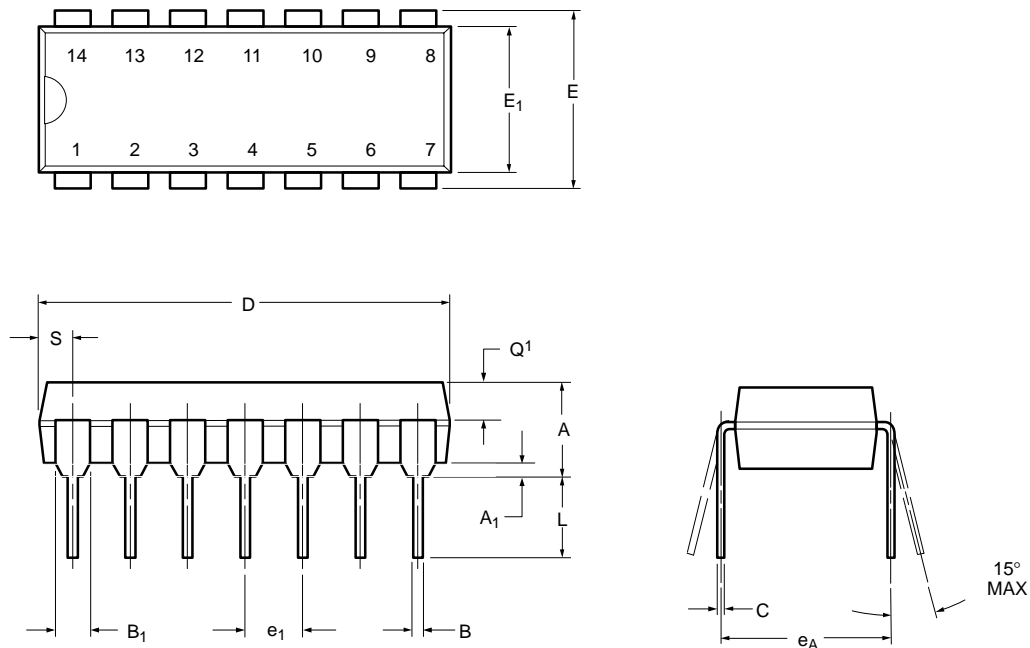
Dim	MILLIMETERS		INCHES	
	Min	**Max**	**Min**	**Max**
A	3.81	5.08	0.150	0.200
A_1	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B_1	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	17.27	19.30	0.680	0.760
E	7.62	8.26	0.300	0.325
E_1	5.59	7.11	0.220	0.280
e_1	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q_1	1.27	2.03	0.050	0.080
S	1.02	2.03	0.040	0.080

ECN: S-03946—Rev. C, 09-Jul-01
DWG: 5481

RECOMMENDED MINIMUM PADS FOR SO-14

0.322
(8.179)

0.047
(1.194)

0.246
(6.248)

0.152
(3.861)

0.022
(0.559)

0.050
(1.270)

0.028
(0.711)
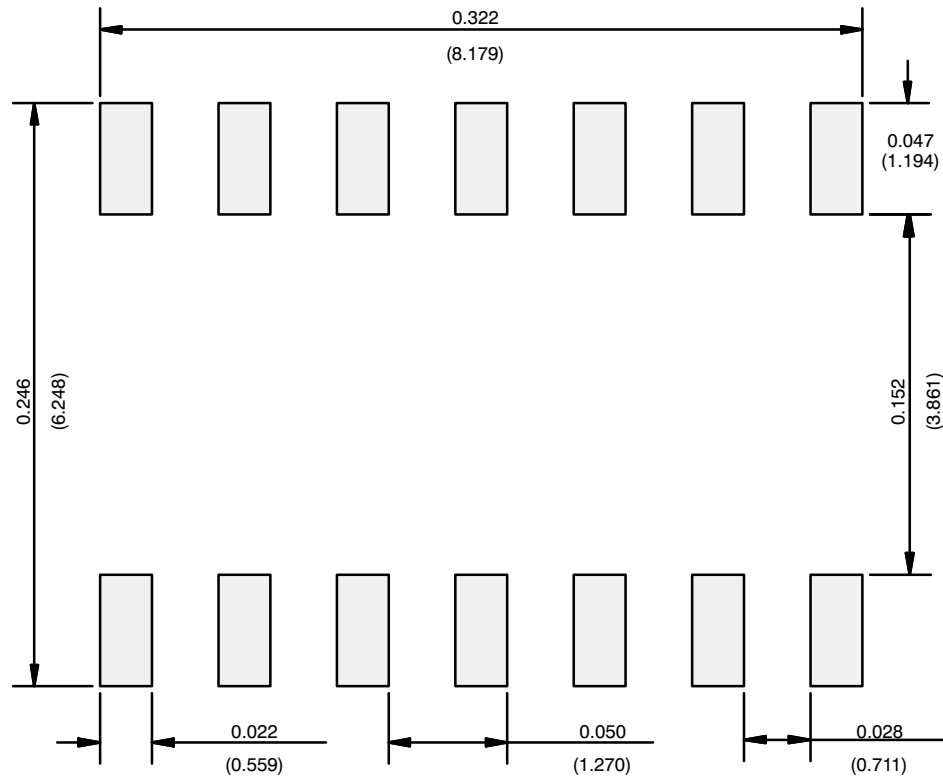
Recommended Minimum Pads
Dimensions in Inches/(mm)

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APPLICATION NOTE

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